

Vishay Siliconix

N-Channel 30 V (D-S) 175 °C MOSFET

DESCRIPTION

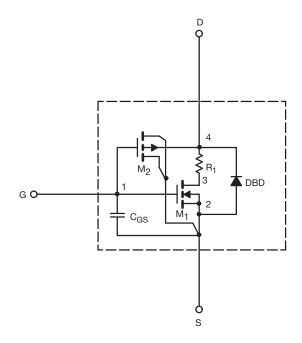
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}$ C to 125 $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model SUM85N03-06P

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SPECIFICATIONS ($T_J = 25 ^{\circ}\text{C}$,	1	,	OINALU ATER	MEACURES	
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.8	-	V
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	923	-	Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A	0.0044	0.0053	Ω
		V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C	0.0080	-	
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$	0.0077	0.0078	
Diode Forward Voltage	V_{SD}	I _S = 100 A, V _{GS} = 0 V	0.89	1.2	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	3155	3100	pF
Output Capacitance	C _{oss}		509	565	
Reverse Transfer Capacitance	C _{rss}		177	255	
Total Gate Charge	Qg	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 50 A	47	48	nC
Gate-Source Charge	Q_{gs}		10	10	
Gate-Drain Charge	Q_{gd}		7.5	7.5	
Turn-On Delay Time	t _{d(on)}	$V_{DD} = 15 \text{ V}, \text{ R}_{L} = 0.3 \Omega$ $I_{D} = 50 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 2.5 \Omega$ $I_{F} = 50 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$	10	12	ns
Rise Time	t _r		14	12	
Turn-Off Delay Time	t _{d(off)}		26	30	
Fall Time	t _f		33	10	
Source-Drain Reverse Recovery Time	t _{rr}		31	35	

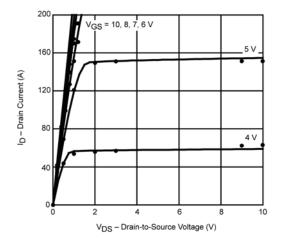
Notes

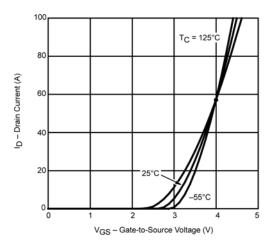
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

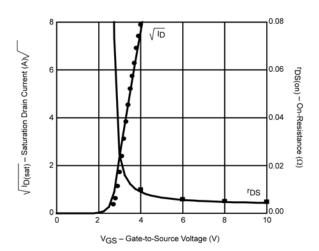
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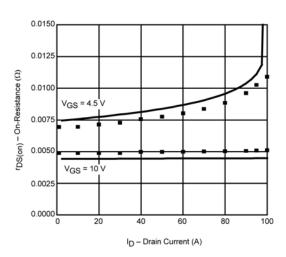
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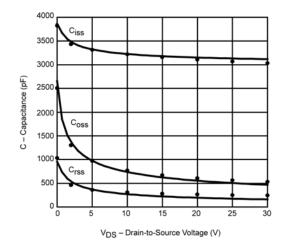
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25$ °C, unless otherwise noted)

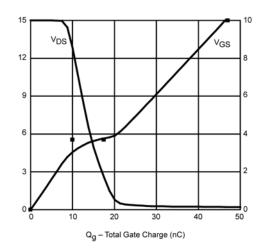












Note

• Dots and squares represent measured data.



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